

Intel[®] Solid-State Drive 750 Series

- Capacities
 - 400GB, 1.2TB
- PCIe* Gen3 x4
- Form Factor
 - 2.5-inch Form Factor
 - 15mm Z-height
 - 8639-compatible connector
 - Add-in Card (AIC) Form Factor
 - Half-height, Half-length
 - Single slot x4 connector
- Performance^{1,2}
 - Seq R/W: Up to 2400/1200 MB/s³
 - 4K Random Read: Up to 440K
 - 4K Random Write: Up to 290K
- Latency (average sequential)
 - Read: 20 μs (TYP)
 - Write: 20 μs (TYP)
- Components
 - Intel® 20nm MLC NAND Flash Memory
- Operating System Support:
 - Windows 7* 64 bit
 - Windows 8* 64 bit
 - Windows 8.1* 64 bit
 - UEFI* 2.3.1 or later
- Reliability
 - Uncorrectable Bit Error Rate (UBER):
 1 sector per 10¹⁶ bits read
 - Mean Time Before Failure (MTBF):
 1.2 million hours
- Power
 - 2.5-inch: 3.3V and 12V Supply Rail
 - AIC: 3.3V and 12V Supply Rail
 - Enhanced power-loss data protection
 - Active/Idle (TYP): 25W/4W (TYP)

Product Specification

- Compliance
 - NVM Express* 1.0
 - PCI Express* Base Specification Rev 3.0
 - SFF 8639 Enterprise SSD Form Factor Version 1.0a
 - PCI Express Card Electro-Mechanical* (CEM) Specification Rev 2.0
- Certifications and Declarations
 - UL*, CE*, C-Tick*, BSMI*, KCC*, Microsoft WHQL*, VCCI*
- Endurance Rating
 - 70 GB Writes Per Day
 - Up to 219 TBW (Terabytes Written)⁵
- Temperature Specification
 - Operating:
 - AIC: 0 to 55° C
 - 2.5-inch: 0 to 70° C
 - Non-Operating⁶: -55 to 95° C
 - Temperature monitoring
- Weight
 - AIC: up to 195 gm
 - 2.5-inch: up to 125 gm
- Shock
 - 2.5-inch: 1,000 G/0.5msec
 - AIC: 50 G Trapezoidal, 170 in/s
- Vibration
 - Operating: 2.17 G_{RMS} (5-700Hz)
 - Non-Operating: 3.13 G_{RMS} (5-800Hz)
- Altitude (Simulated)
 - Operating: -1,000 to 10,000 ft
 - Non-Operating: -1,000 to 40,000 ft
- Product Ecological Compliance
 - RoHS

- 1. Performance values vary by capacity and form factor
- 2. Performance specifications apply to both compressible and incompressible data
- 3. MB/s = 1,000,000 bytes/second
- 4. 4KB = 4,096 bytes; 8 KB = 8,192 bytes
- 5. 1PB = 10¹⁵ Bytes
- 6. Please contact your Intel representative for details on the non-operating temperature range

Intel[®] Solid-State Drive 750 Series



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Tests document performance of components on a particular test, in specific systems. Differences in hardware, software, or configuration will affect actual performance. Consult other sources of information to evaluate performance as you consider your purchase.

Test and System Configuration: Processor: Intel Core i7-4790K, Speed: 4.0 GHz, Chipset: Intel Z97, Motherboard: ASUS z97-Deluxe, DRAM capacity: 4GB, DRAM Speed: DDR3 2133 MHz, OS: Windows* 8.1.

For more complete information about performance and benchmark results, visit http://www.intel.com/performance.

All documented performance test results are obtained in compliance with JESD218 Standards; refer to individual sub-sections within this document for specific methodologies. See <u>www.jedec.org</u> for detailed definitions of JESD218 Standards.

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1 **Overview**

This document describes the specifications and capabilities of the Intel® Solid State Drive 750 Series (Intel® SSD 750 Series).

The Intel SSD 750 Series is Intel's first PCIe* Gen3 x4 SSD developed for the client enthusiast and workstation markets. The Intel SSD 750 Series is architected with the new high performance controller interface - Non-Volatile Memory Express* (NVMe*) - delivering outstanding performance, low latency and Quality of Service. NVMe is a standardized interface that enables higher performance and lower latency than previous generations. The Intel SSD 750 Series offers capacities of 400GB and 1.2TB in Add-In card and 2.5-inch (SFF-8639 connector) form factors.

The Intel SSD 750 Series is Intel's highest performing client drive specifically designed for the PC enthusiast and workstation systems with demanding storage workstation requirements. With PCIe Gen3 x4 support and NVMe queuing interface, the Intel SSD 750 Series delivers excellent sequential read performance of up to 2.4 GB/s and sequential write speeds of up to 1.2 GB/s. The Intel SSD 750 Series delivers random read IOPS of up to 440K and random write IOPS of up to 290K for 4KB operations. Also, by taking advantage of the direct path from the storage to the CPU by means of NVMe, the Intel SSD 750 Series exhibits low latency of less than 20 µs for sequential access to the SSD.

Intel SSD 750 Series includes these key features:

- PCIe Gen3 x4 with NVMe interface
- Consistently Higher IOPS and throughput
- Sustained low latency
- Enhanced power-loss data protection



Revision History

Revision Number	Description	Revision Date
001	• Initial release	April 2015

1.1 References

Table 1: Standard Information Referenced in this Document

Date	Title	Location
Jan 2013	SFF 8639 Enterprise SSD Form Factor Version 1.0a	http://www.ssdformfactor.org
Feb 2012	NVMe Revision 1.0c	http://www.nvmexpress.org
Nov 2010	PCIe Base Specification Revision 3.0	http://pcisig.com
July 2012	Solid-State Drive (SSD) Requirements and Endurance Test Method (JESD219)	http://www.jedec.org/standards- documents/results/jesd219
Sept 2010	Solid-State Drive (SSD) Requirements and Endurance Test Method (JESD218)	http://www.jedec.org/standards- documents/docs/jesd218/
Dec 2008	vccı	http://www.vcci.jp/vcci_e/
June 2009	RoHS	http://qdms.intel.com/ Click <i>Search MDDS Database</i> and search for material description datasheet
1995International Electrotechnical Commission EN 6100019954-2 (Electrostatic discharge immunity test)19964-3 (Radiated, radio-frequency, electromagnetic field immunity test)19954-4 (Electrical fast transient/burst immunity test)19954-5 (Surge immunity test)19974-6 (Immunity to conducted disturbances, induced by radio-frequency fields)19944-11 (Voltage Variations, voltage dips, short interruptions and voltage variations immunity tests)		http://www.iec.ch/
1995	ENV 50204 (Radiated electromagnetic field from digital radio telephones)	http://www.dbicorporation.com/ radimmun.htm/



1.2 Terms and Acronyms

Table 2: Glossary of Terms and Acronyms

Term	Definition		
ATA	Advanced Technology Attachment		
CRC	Cyclic Redundancy Check		
DAS	Device Activity Signal		
DMA	Direct Memory Access		
ECC	Error Correction Code		
EEPROM	Electrically Erasable Programmable Read Only Memory		
EXT	Extended		
FPDMA	First Party Direct Memory Access		
GB	Gigabyte Note: The total usable capacity of the SSD may be less than the total physical capacity because a small portion of the capacity is used for NAND flash management and maintenance purposes.		
Gb	Gigabit		
HDD	Hard Disk Drive		
HET	High Endurance Technology		
КВ	Kilobyte		
I/O	Input/Output		
IOPS	Input/Output Operations Per Second		
ISO	International Standards Organization		
LBA	Logical Block Address		
MB	Megabyte (1,000,000 bytes)		
MLC	Multi-level Cell		
MTBF	Mean Time Between Failures		
NOP	No Operation		
NVMe	Non-Volatile Memory Express		
PB	Petabyte		
PCB	Printed Circuit Board		
RDT	Reliability Demonstration Test		
RMS	Root Mean Square		
SSD	Solid-State Drive		
ТВ	Terabyte		
TYP	Typical		
UBER	Uncorrectable Bit Error Rate		
VPD	Vital Product Data		





2 **Product Specifications**

2.1 Capacity

Table 3: User Addressable Sectors

Intel SSD 750 Series	Unformatted Capacity (Total User Addressable Sectors in LBA Mode)
400GB	781,422,768
1.2TB	2,344,225,968

NOTES:

1 GB = 1,000,000,000 bytes; 1 sector = 512 bytes

LBA count shown represents total user storage capacity and will remain the same throughout the life of the drive. The total usable capacity of the SSD may be less than the total physical capacity because a small portion of the capacity is used for NAND media management and maintenance. IDEMA or JEDEC standard is used.

2.2 Performance

Table 4:Performance1

Encolfication 1	Unit -	Intel SSD 750 Series	
Specification ¹		400GB	1.2TB
Random 4KB ² Read (up to)	IOPS	430,000	440,000
Random 4KB Write (up to)	IOPS	230,000	290,000
Sequential 128KB Read ³	MB/s ⁴	2,200	2,400
Sequential 128KB Write	MB/s	900	1,200

- 1. Performance measured by Intel using IOMeter* on Intel provided NVMe driver with Queue Depth 128 (QD=32, workers=4). Measurements are performed on a contiguous 8GB span of the drive on a full SSD. Power mode set at 25W.
- 2. 4KB = 4,096 bytes
- 3. Performance measured by Intel using IOMeter* with 128 KB (131,072 bytes) of transfer size with Queue Depth 128. Power mode set at 25W.
- 4. MB/s = 1,000,000 bytes/second



Table 5: Latency

Constituention	Intel SSD 750 Series		
Specification	Sequential	Random	
Read ¹	20 µs (TYP)	120 μs (TYP)	
Write ¹	20 µs (TYP)	45 μs (TYP)	
Typical Power On to First I/O Completion ²	Up to 10) seconds	
Typical Reset to First I/O Completion ³	Up to 15 seconds		

NOTES:

- 1. Device measured by Intel using IOMeter*. Latency measured using 4 KB (4,096 bytes) transfer size with Queue Depth equal to 1 using Windows 8.1 driver. Power mode set at 25W.
- 2. Assumes clean shutdown,. Time to complete first I/O from complete power off state.
- 3. Time to complete first I/O after start of NVMe Controller Reset.

2.3 Electrical Characteristics

Table 6: Operating Voltage

Electrical Characteristics	Intel SSD 750 Series	
3.3V Operating Characteristics: (Add-in Card only)	2.2.1/(140%)	
Operating Voltage range	3.3 V (±10%)	
Rise time (Max/Min)	50ms/1ms	
Fall time (Max/Min) ¹	5s/1ms	
Noise level	300 mV pp 10Hz – 100 KHz	
	50 mV pp 100KHz – 20 MHz	
Min Off time ²	500 ms	
Max Average Current	3.0 A	
12V Operating Characteristics:		
Operating Voltage range	12 V (+10%/-20%)	
Rise time (Max/Min)	50ms/1ms	
Fall time (Max/Min) ¹	5s/1ms	
Noise level	1000 mV pp 10Hz – 100 KHz	
	100 mV pp 100KHz – 20 MHz	
Min Off time ²	500 ms	
Max Average Current	2.1 A	

- 1. Fall time needs to be equal or better than minimum in order to guarantee full functionality of enhanced power loss management.
- 2. The drive must be powered off for at least 500msec before powering on.



Table 7: Power Consumption

Specification	Unit	Intel SSD 750 Series	
		400GB	1.2TB
Active Write – Average ¹	w	12	22
Active Read – Average ²	w	9	10
Idle	W	4	4

NOTES:

- 1. The workload equates 64KB (65,536 bytes) Queue Depth equal to 128 sequential writes. Average power is measured by Intel using scope trigger over a 100 ms sample period.
- 2. The workload equates 64KB (65,536 bytes) Queue Depth equal to 128 sequential reads.

2.4 Environmental Conditions

Table 8: Temperature, Shock, Vibration

Temperature	Add-In card form factor	2.5-inch form factor
Temperature Operating ¹ Non-operating ²	0 – 55° C -55–95° C	0–35° C 0-70 ° C
Temperature Gradient ³ Operating Non-operating	30° C/hr (Typical) 30° C/hr (Typical)	30° C/hr (Typical) 30° C/hr (Typical)
Humidity Operating Non-operating	5–95% 5–95%	5–95% 5–95%
Shock and Vibration	Rai	nge
Shock ⁴ Operating Non-operating	50 G Trapezoidal, 170 in/s 50 G Trapezoidal, 170 in/s	1,000 G (Max) at 0.5 msec 1,000 G (Max) at 0.5 msec
Vibration ⁵ Operating Non-operating	2.17 G _{RMS} (5-700 Hz) Max 3.13 G _{RMS} (5-800 Hz) Max	2.17 G _{RMS} (5-700 Hz) Max 3.13 G _{RMS} (5-800 Hz) Max

- 1. Operating temperature implies ambient air temperature with certain airflow conditions.
- 2. Please contact your Intel representative for details on the non-operating temperature range.
- 3. Temperature gradient measured without condensation.
- 4. Shock specifications assume the SSD is mounted securely with the input vibration applied to the drive-mounting screws. Stimulus may be applied in the X, Y or Z axis. Shock specification is measured using Root Mean Squared (RMS) value.
- 5. Vibration specifications assume the SSD is mounted securely with the input vibration applied to the drive-mounting screws. Stimulus may be applied in the X, Y or Z axis. Vibration specification is measured using RMS value.



2.5 Product Regulatory Compliance

Intel SSD 750 Series meets or exceeds the regulatory or certification requirements in the following table.

Table 9: Product Regulatory Compliance Specifications

Title	Description	Region For Which Conformity Declared
ICES-003, Issue 4 Interference-Causing Equipment Standard Digital Apparatus	CA/CSA-CEI/IEC CISPR 22-10 (Ref. CISPR 22:2008)	Canada
IEC 55024 Information Technology Equipment – Immunity characteristics – Limits and methods of measurement CISPR24:2010	EN-55024: 2010 and its amendments	European Union
IEC 55022 Information Technology Equipment – Radio disturbance Characteristics – Limits and methods of measurement CISPR24:2008 (Modified)	EN-55022: 2010 and its amendments	European Union
EN-60950-1 2 nd Edition	Information Technology Equipment – Safety – Part 1: General Requirements	USA/Canada
UL/CSA EN-60950-1 2 nd Edition	Information Technology Equipment – Safety – Part 1: General Requirements	USA/Canada

2.6 Reliability Specifications

Intel SSD 750 Series meets or exceeds SSD endurance and data retention requirements as specified in the JESD218 standard. Reliability specifications are listed in the following table.

Table 10: Reliability Specifications

Parameter	Value
Uncorrectable Bit Error Rate (UBER) Uncorrectable bit error rate will not exceed one sector in the specified number of bits read. In the unlikely event of a non-recoverable read error, the SSD will report it as a read failure to the host; the sector in error is considered corrupt and is not returned to the host.	< 1 sector per 10 ¹⁶ bits read
Mean Time Between Failures (MTBF) Mean Time Between Failures is estimated based on Telcordia* methodology and demonstrated through Reliability Demonstration Test (RDT).	1.2 million hours
Data Retention The time period for retaining data in the NAND at maximum rated endurance.	3 months power-off retention once SSD reaches rated write endurance at 40 °C
Endurance Rating The SSD will have a minimum useful life based on a typical client workload assuming up to 70GB of host writes per day.	5 years



3 Mechanical Information

Figures 3-1 and 3-2 show the physical package information for the Intel SSD 750 Series in the 2.5-inch form factors. All dimensions are in millimeters.



Figure 3-1 Intel SSD 750 Series SFF Dimensions

Note: Drawing may not reflect final product. Length does not include 0.3 connector protrusion.



Figure 3-2 Intel SSD 750 Series PCIe Dimensions





Note: Drawing may not reflect final product.



4 Pin and Signal Descriptions

4.1 2.5-inch Form Factor Pin Locations

Figure 4-1 2.5-inch Form Factor Pin Locations



Note: 2.5-inch connector supports built in latching capability.

4.2 Pin Signal Definitions

Table 11: Pin Definition for 2.5-inch Form Factor (8639 connector specification)

Pin	Name	Description	Pin	Name	Description
S1	GND	Ground	E7	REFCLK0+	Reference clock port 0
S2		Not used (SATA/SAS)	E8	REFCLK0-	Reference clock port 0
S3		Not used (SATA/SAS)	E9	GND	Ground
S4	GND	Ground	E10	PETp0	Transmitter differential pair, Lane 0
S5		Not used (SATA/SAS)	E11	PETn0	Transmitter differential pair, Lane 0
S6		Not used (SATA/SAS)	E12	GND	Ground
S7	GND	Ground	E13	PERn0	Receiver differential pair, Lane 0
E1	REFCLK1+	Reference clock port 1 (not used)	E14	PERp0	Receiver differential pair, Lane 0
E2	REFCLK1-	Reference clock port 1 (not used)	E15	GND	Ground
E3	3.3Vaux	3.3V auxiliary power (Optional)	E16	RSVD	Reserved
E4	PERST1#	Fundamental reset port 1 (not used)	S8	GND	Ground
E5	PERST0#	Fundamental reset port 0	S9		Not used (SATAe/SAS)
E6	RSVD	Reserved	S10		Not used (SATAe/SAS)
P1		Not used (SATAe/SAS)	S11	GND	Ground
P2		Not used (SATAe/SAS)	S12		Not used (SATAe/SAS)
P3		Not used (SATAe)	S13		Not used (SATAe/SAS)
Ρ4	lfDet_N	Interface detect (drive type)	S14	GND	Ground



Pin	Name	Description	Pin	Name	Description
P5	GND	Ground	S15	RSVD	Reserved
P6	GND	Ground	S16	GND	Ground
P7		Not used (SATA/SAS)	S17	PETp1	Transmitter differential pair, Lane 1
P8		Not used (SATA/SAS)	S18	PETn1	Transmitter differential pair, Lane 1
P9		Not used (SATA/SAS)	S19	GND	Ground
P10	PRSNT_N	Presence detect (also used for drive type)	S20	PERn1	Receiver differential pair, Lane 1
P11	Activity	Activity signal from the drive	S21	PERp1	Receiver differential pair, Lane 1
P12	Hot-Plug	Ground	S22	GND	Ground
P13	+12V_pre	12V power	S23	PETp2	Transmitter differential pair, Lane 2
P14	+12V	12V power	S24	PETn2	Transmitter differential pair, Lane 2
P15	+12V	12V power	S25	GND	Ground
			S26	PERn2	Receiver differential pair, Lane 2
			S27	PERp2	Receiver differential pair, Lane 2
			S28	GND	Ground
			E17	PETp3	Transmitter differential pair, Lane 3
			E18	PETn3	Transmitter differential pair, Lane 3
			E19	GND	Ground
			E20	PERn3	Receiver differential pair, Lane 3
			E21	PERp3	Receiver differential pair, Lane 3
			E22	GND	Ground
			E23		Not used/NC (SMBus clock)
			E24		Not used/NC (SMBus data)
			E25	DualPortEn_N	Dual port enable

- PRSNT_N is kept open by the Intel SSD 750 Series.
- IfDet_N is grounded by Intel SSD 750 Series.
- DualPortEn_N pin should be left un-connected or un-driven by the system to enable single port operation with all 4 lanes. If un-connected, Intel SSD 750 will pull it high. However, if the pin is asserted by the system (driven low by storage backplane), then Intel SSD DC S3700 will be configured as x2 lanes.
- P11 can be used for activity signal from Intel SSD 750 Series.
- Intel SSD 750 Series only uses REFCLKO+ and REFCLKO- as reference clock pair.
- Intel SSD 750 Series only uses PERSTO# as a fundamental reset.



Table 12: Pin Definition for Add-In Card (Half Height Half Length) Form Factor

	Side B			Side A
Pin	Name	Description	Name	Description
1	+12V	12V power	PRSNT1#	Hot-Plug presence detect
2	+12V	12V power	+12V	12V power
3	+12V	12V power	+12V	12V power
4	GND	Ground	GND	Ground
5	SMCLK	Not used/NC (SMBus (System Management Bus) clock)	JTAG2	TCK (Test Clock), clock input for JTAG interface
6	SMDAT	Not used/NC (SMBus (System Management Bus) data)	JTAG3	TDI (Test Data Input)
7	GND	Ground / UART_HOST	JTAG4	TDO (Test Data Output)
8	+3.3V	3.3V power	JTAG5	TMS (Test Mode Select)
9	JTAG1	TRST# (Test Reset) resets the JTAG interface	+3.3V	3.3V power
10	3.3Vaux	3.3V auxiliary power (Optional)	+3.3V	3.3V power
11	WAKE#	Signal for Link reactivation	PERST#	Fundamental reset
	•	Mechanical Key		·
12	RSVD	Reserved	GND	Ground
13	GND	Ground	REFCLK+	Reference clock (differentialpair)
14	PETp0	Transmitter differential pair, Lane 0	REFCLK-	Reference clock (differentialpair)
15	PETn0	Transmitter differential pair, Lane 0	GND	Ground
16	GND	Ground	PERp0	Receiver differential pair, Lane 0
17	PRSNT2#	Hot-Plug presence detect	PERn0	Receiver differential pair, Lane 0
18	GND	Ground	GND	Ground
		End of the x1 Conne	ector	
19	PETp1	Transmitter differential pair, Lane 1	RSVD	Reserved
20	PETn1	Transmitter differential pair, Lane 1	GND	Ground
21	GND	Ground	PERp1	Receiver differential pair, Lane 1
22	GND	Ground	PERn1	Receiver differential pair, Lane 1
23	PETp2	Transmitter differential pair, Lane 2	GND	Ground
24	PETn2	Transmitter differential pair, Lane 2	GND	Ground
25	GND	Ground	PERp2	Receiver differential pair, Lane 2
26	GND	Ground	PERn2	Receiver differential pair, Lane 2
27	PETp3	Transmitter differential pair, Lane 3	GND	Ground
28	PETn3	Transmitter differential pair, Lane 3	GND	Ground
29	GND	Ground	PERp3	Receiver differential pair, Lane 3
30	RSVD	Reserved	PERn3	Receiver differential pair, Lane 3
31	PRSNT2#	Hot-Plug presence detect	GND	Ground
32	GND	Ground	RSVD	Reserved

- All pins are numbered in ascending order from the left to the right, with side A on the top of the centerline and side B on the bottom of the centerline, use the reference drawing in Fig2, with the logo visible.
- The PCI Express interface pins PETpx, PETnx, PERpx, and PERnx are named with the following convention: "PE" stands for PCI Express high speed, "T" for Transmitter, "R" for Receiver, "p" for positive (+) and "n" for negative (-).
- The sequential mating for Hot-Plug is accomplished by staggering the edge fingers on the add-in card.



5 Supported Command Sets

Intel SSD 750 Series supports all mandatory Admin and I/O commands defined in NVMe (Non-Volatile Memory Express) revision 1.0.

5.1 NVMe Admin Command Set

The Intel SSD 750 Series supports all mandatory NVMe commands, which are:

- Delete I/O Submission Queue
- Delete I/O Completion Queue
- Create I/O Submission Queue
- Create I/O Completion Queue
- Get Log Page
- Identify
- Abort
- SET Features
- GET Features
- Asynchronous Event Notification

Intel SSD 750 Series also supports the following optional I/O commands defined in NVMe revision 1.0:

- Firmware Activate
- Firmware Image Download
- Format NVM

Note: See Appendix A, "Identify Controller Data Structure" for details on commands and capabilities.

5.2 NVMe I/O Command Set

Intel SSD 750 Series supports all the mandatory NVMe I/O command set defined in NVMe 1.0 specification, which are:

- Flush
- Write
- Read

Additionally, the following optional commands are supported:

- Write Uncorrectable
- Dataset Management (De-allocate only)



5.3 Log Page Support

Intel SSD 750 Series supports the following mandatory log pages defined in NVMe 1.0 specification:

- Error Information (Log Identifier 01h)
- SMART/ Health Information (Log Identifier 02h)
- Firmware Slot Information (Log Identifier 03h)

Note: See NVMe 1.0 version of the specification for the log page content.

Additionally, Intel SSD 750 Series will support the following vendor unique log pages:

- Log Page Directory (Log Identifier C0h)
- Temperature Statistics (Log Identifier C5h)
- Vendor Unique SMART Log (Log Identifier CAh)

5.4 SMART Attributes

The following table lists the SMART attributes supported by the Intel SSD 750 Series in accordance with NVMe 1.0 specification.

Table 13: SMART Attributes (Log Identifier 02h)

Byte	# of Bytes	Attribute	Description
0	1	Critical Warning: These bits if set, flag various warning sources. Bit 0: Available Spare is below Threshold Bit 1: Temperature has exceeded Threshold Bit 2: Reliability is degraded due to excessive media or internal errors Bit 3: Media is placed in Read- Only Mode Bit 4: Volatile Memory Backup System has failed (e.g., enhanced power loss capacitor test failure) Bits 5-7: Reserved	Any of the critical warning can be tied to asynchronous event notification.
1	2	Temperature: Overall Device current temperature in Kelvin.	For AIC, it reports the NAND temperature, for 2.5-inch FF, it is the case temperature.
3	1	Available Spare: Contains a normalized percentage (0 to 100%) of the remaining spare capacity available	Starts from 100 and decrements.
4	1	Available Spare Threshold	Threshold is set to 10%.
5	1	Percentage Used Estimate (Value allowed to exceed 100%)	A value of 100 indicates that the estimated endurance of the device has been consumed, but may not indicate a device failure. The value is allowed to exceed 100. Percentages greater than 254 shall be represented as 255. This value shall be updated once per power-on hour (when the controller is not in a sleep state).



Byte	# of Bytes	Attribute	Description
32	16	Data Units Read (in LBAs)	Contains the number of 512 byte data units the host has read from the controller; this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds to 1000 units of 512 bytes read) and is rounded up. When the LBA size is a value other than 512 bytes, the controller shall convert the amount of data read to 512 byte units.
48	16	Data Units Write (in LBAs)	Contains the number of 512 byte data units the host has written to the controller; this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds to 1000 units of 512 bytes written) and is rounded up. When the LBA size is a value other than 512 bytes, the controller shall convert the amount of data written to 512 byte units. For the NVM command set, logical blocks written as part of Write operations shall be included in this value. Write Uncorrectable commands shall not impact this value.
64	16	Host Read Commands	Contains the number of read commands issued to the controller.
80	16	Host Write Commands	Contains the number of write commands issued to the controller.
96	16	Controller Busy Time (in minutes)	Contains the amount of time the controller is busy with I/O commands. The controller is busy when there is a command outstanding to an I/O Queue (specifically, a command was issued by way of an I/O Submission Queue Tail doorbell write and the corresponding completion queue entry
			has not been posted yet to the associated I/O Completion Queue). This value is reported in minutes.
112	16	Power Cycles	Contains the number of power cycles.
128	16	Power On Hours	Contains the number of power-on hours. This does not include time that the controller was powered and in a low power state condition.
144	16	Unsafe shutdowns	Contains the number of unsafe shutdowns. This count is incremented when a shutdown notification (CC.SHN) is not received prior to loss of power.
160	16	Media Errors	Contains the number of occurrences where the controller detected an unrecovered data integrity error. Errors such as uncorrectable ECC, CRC checksum failure, or LBA tag mismatch are included in this field.
176	16	Number of Error Information Log Entries	Contains the number of Error Information log entries over the life of the controller.





Byte	# of Bytes	Attribute	Description
0	1	AB (Program Fail Count)	Raw value: shows total count of
3	1	Normalized Value	program fails. Normalized value: beginning at 100,
5	6	Current Raw Value	shows the percent remaining of allowable program fails.
12	1	AC (Erase Fail Count)	Raw value: shows total count of erase
15	1	Normalized Value	fails. Normalized value: beginning at 100,
17	6	Current Raw Value	shows the percent remaining of allowable erase fails.
24	1	AD (Wear Leveling Count)	Raw value:
27	1	Normalized Value	Bytes 1-0: Min. erase cycle
29	6	Current Raw Value	Bytes 3-2: Max. erase cycle Bytes 5-4: Avg. erase cycles Normalized value: decrements from 100 to 0.
36	1	B8 (End to End Error Detection Count)	Raw value: reports number of End-to-
39	1	Normalized Value	End detected and corrected errors by hardware.
41	6	Current Raw Value	Normalized value: always 100.
48	1	C7 (CRC Error Count)	Raw value: shows total number of
51	1	Normalized Value	encountered SATA interface cyclic redundancy check (CRC) errors.
53	6	Current Raw Value	Normalized value: always 100.
60	1	E2 (Timed Workload, Media Wear)	Raw value: measures the wear seen b
63	1	Normalized Value	the SSD (since reset of the workload timer, attribute E4h), as a percentage
65	6	Current Raw Value	the maximum rated cycles. Divide the raw value by 1024 to derive the percentage with 3 decimal points. Normalized value: always 100.
72	1	E3 (Timed Workload, Host Reads %)	Raw value: shows the percentage of I,
75	1	Normalized Value	operations that are read operations (since reset of the workload timer,
77	6	Current Raw Value	attribute E4h). Reported as integer percentage from 0 to 100. Normalized value: always 100.
84	1	E4 (Timed Workload, Timer)	Raw value: measures the elapsed time
87	1	Normalized Value	(number of minutes since starting this workload timer).
89	6	Current Raw Value	Normalized value: always 100.
96	1	EA (Thermal Throttle Status)	Raw value: reports Percent Throttle
99	1	Normalized Value	Status and Count of events
101	6	Current Raw Value	Byte 0: Throttle status reported as integer percentage. Bytes 1-4: Throttling event count. Number of times thermal throttle has activated. Preserved over power cycle Byte 5: Reserved. Normalized value: always 100.

Table 14: Additional SMART Attributes (Log Identifier CAh)



5.5 Temperature Statistics

Table 15: Temperature Statistics (Log Identifier C5h)

Byte	# of Bytes	Description	
0	1	Current Temperature	
24	8	Highest temperature	
32	8	Lowest temperature	
80	8	Specified Maximum Operating Temperature	
96	8	Specified Minimum Operating Temperature	

Note: All temperature values indicate internal temperature sensor values. Add-in Card reports NAND temperature, 2.5-inch form factor reports case temperature.

5.6 SET Feature Identifiers

In addition to the SMART attribute structure, features pertaining to the operation and health of the Intel SSD 750 Series can be reported to the host on request through the Get Features command. Intel SSD 750 Series can change settings using SET Features on the following items as defined in NVMe 1.0 specification.

- Arbitration (Feature Identifier 01h)
- Power Management (Feature Identifier 02h)
- Temperature Threshold (Feature Identifier 04h)
- Error Recovery (Feature Identifier 05h)
- Volatile Write Cache (Feature Identifier 06h)
- Number of Queues (Feature Identifier 07h)
- Interrupt Coalescing (Feature Identifier 08h)
- Interrupt Vector Configuration (Feature Identifier 09h)
- Write Atomicity (Feature Identifier 0Ah)
- Asynchronous Event Configuration (Feature Identifier OBh)

Intel SSD 750 Series will also support the following vendor unique SET Features.

- Set/Get Max LBA (Feature Identifier C1h)
- Set/Get Native Max LBA (Feature Identifier C2h)
- Power Governor Setting (Feature Identifier C6h)
- Reset Timed Workload Counters (Feature Identifier D5h)



Table 16: Set Max LBA Setting - Command Dword 11 and Command Dword 12

Bit	Description
63:00	Maximum User LBA: Write Usage: This field sets the 64-bit maximum LBA addressable by the Drive.
	Read Usage: This field contains the 64-bit maximum LBA addressable by the Drive.
	Command Dword 11 contains bits 31:00; Command Dword 12 contains bits 63: 32.

Table 17: Status Code - Set Max LBA Command Specific Status Values

Value	Description
C0h	Requested MAX LBA exceeds Available capacity
C1h	Requested MAX LBA smaller than minimum allowable limit.
C2h	Requested MAX LBA is smaller than allocated Namespace requirements

Table 18: D5h - Reset Timed Workload Counters - Command Dword 11

Bit	Description
31:01	Reserved
00	Timed Workload Reset Settings: Write Usage: 00 = NOP, 1 = Reset E2, E3,E4 counters; Read Usage: Not Supported

Note: Get Features will not work for "Reset Timed Workload Counters" and status code is same as Table 21.



6 **NVMe Driver Support**

The following table describes the NVMe Driver Support for Intel SSD 750 Series. The support includes releasing and validating NVMe drivers for certain operating systems and validating functionality for open source drive, inbox or native drivers for select operating systems.

Table 19: NVMe Driver Support

Support Level	Operating System Description
Intel Provided ¹	Windows 7* 64 bit, Windows 8* 64 bit, Windows 8.1* 64 bit
Other Driver ²	Window 7* 64 bit, Windows 8* 64 bit, Windows 8.1* 64 bit, Linux Kernel 3.10 or later

NOTES:

1. With Intel provided driver, full product specification is provided and recommended.

2. With open source non-Intel driver, compatibility and functionality are validated.



7 Certifications and Declarations

Table 20: Device Certifications and Declarations

Certification	Description
CE Compliant	European Economic Area (EEA): Compliance with the essential requirements of EC Council Directives Low Voltage Directive (LVD) 2006/95/EC, EMC Directive 2004/108/EC and Directive 2011/65/EU.
UL Recognized	Certified Underwriters Laboratories, Inc. Bi-National Component Recognition; UL 60950-1, 2nd Edition, 2007- 03-27 (Information Technology Equipment - Safety - Part 1: General Requirements) CSA C22.2 No. 60950-1-07, 2nd Edition, 2007-03 (Information Technology Equipment - Safety - Part 1: General Requirements)
C-Tick Compliant	Compliance with the Australia/New Zealand Standard AS/NZS3548 and Electromagnetic Compatibility (EMC) Framework requirements of the Australian Communication Authority (ACA).
BSMI Compliant	Compliance to the Taiwan EMC standard CNS 13438: Information technology equipment - Radio disturbance Characteristics - limits and methods of measurement, as amended on June 1, 2006, is harmonized with CISPR 22: 2005.04.
ксс	Compliance with paragraph 1 of Article 11 of the Electromagnetic Compatibility Control Regulation and meets the Electromagnetic Compatibility (EMC) Framework requirements of the Radio Research Laboratory (RRL) Ministry of Information and Communication Republic of Korea.
vcci	Voluntary Control Council for Interface to cope with disturbance problems caused by personal computers or facsimile.
Microsoft WHCK	Microsoft Windows Hardware Certification Kit
RoHS Compliant	Restriction of Hazardous Substance Directive
WEEE	Directive on Waste Electrical and Electronic Equipment



Appendix A IDENTIFY Data Structure

Table 21: Identify Controller

Bytes	F = Fixed V = Variable X = Both	Default Value	Interpretation Description		
1-0	F	8086h	Contains the company vendor identifier that is assigned by the PCI SIG	PCI Vendor ID (VID)	
3-2	F	8086h	Contains the company vendor identifier that is assigned by the PCI SIG for subsystem	PCI Subsystem Vendor ID (SSVID)	
23-4	v	varies	Contains the serial number for the NVM subsystem	Serial Number (SN)	
63-24	v	varies	Contains the serial number for the NVM subsystem that is assigned by the vendor as an ASCII string	Model Number (MN)	
71-64	v	varies	Contains the currently active firmware revision for the NVM subsystem	Firmware Revision (FR)	
72	F	Oh	Recommended Arbitration Burst size equals 1	Recommended Arbitration Burst (RAB)	
75-73	F	5CD2E4h	Contains the Organization Unique Identifier (OUI) for the controller vendor	IEEE OUI Identifier (IEEE)	
76	х	Oh	No of multiple PCI Express* interfaces connected to the host, bit 0 determines multiple interface	Multi-Interface Capabilities (MIC)	
77	F	05h	Supports MDTS of 128K	Maximum Data Transfer Size (MDTS)	
255:78				Reserved	
257-256	F	07h	Supports Security Send/Receive, Format NVM and Firmware Activate/Download	Optional Admin Command Support (OACS)	
258	F	03h	Supports up to 3 concurrently outstanding abort commands	Abort Command Limit (ACL)	
259	F	03h	Supports up to 3 concurrently outstanding asynchronous event requests	Asynchronous Event Request Limit (AERL)	
260	х	03h	Single slot Read/write capable	Firmware Updates (FRMW)	
261	х	Oh	SMART/Health Log Support per drive not per namespace	Log Page Attributes (LPA)	
262	F	3Fh	Number of Error Information log entries equals 64	Error Log Page Entries (ELPE)	
263	F	Oh	Number of NVM Express power states equal 1	Number of Power States Support (NPSS)	
264	F	Oh	Configuration settings for Admin Vendor Admin Vendor Specific Common Specific command handling		
511-265				Reserved	
512	F	66h	Required and max submission queue entry size is 64 Byte Submission Queue Entry Size (S		
513	F	44h	Required and max submission queue entry size is 16 Byte Completion Queue Entry Size (CC		





515-514 Reserved 519-516 F 01h Supports single namespace Number of Namespaces (NN) 521-520 F 06h Supports Dataset Management and Write Uncorrectable optional NVMe commands. Optional NVMe Command Support (FUSES) 523-522 F 0h Fused commands not supported Fused Operation Support (FUSES) 524 F 07h Supports Crypto Erase and format of entire drive, not per namespace Format NVM Attributes (FNA): 525 F 0h Volatile write cache is not present Volatile Write Cache (VWC) 527-526 F 0h Atomic write size for controller during normal equals to 5128 Atomic Write Unit Normal (AWUP) 529-528 F 0h Indicates the atomic write size for the controller Atomic Write Unit Normal (AWUP) 530 X 0h Not Supported Reserved Reserved 2047-704 Reserved Indicates the characteristics of power state 0 Power State 1 Descriptor (PSD) 2111-2080 V Indicates the characteristics of power state 1 Power State 4 Descriptor (PSD) 2111-2080 V Indicat	
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2431-2400 V Power State The Description (PSDT)	
2463-2432 V Indicates the characteristics of power state 12 Power State 12 Descriptor (PSD12)	
2495-2464 V Indicates the characteristics of power state 13 Power State 13 Descriptor (PSD13)	
2527-2496 V Indicates the characteristics of power state 14 Power State 14 Descriptor (PSD14)	
2559-2528 V Indicates the characteristics of power state 15 Power State 15 Descriptor (PSD15)	
2591-2560 V Indicates the characteristics of power state 16 Power State 16 Descriptor (PSD16)	
2623-2592 V Indicates the characteristics of power state 17 Power State 17 Descriptor (PSD17)	



Bytes	F = Fixed V = Variable X = Both	Default Value	Interpretation	Description	
2655-2624	V		Indicates the characteristics of power state 18	Power State 18 Descriptor (PSD18)	
2687-2656	V		Indicates the characteristics of power state 19	Power State 19 Descriptor (PSD19)	
2719-2688	V		Indicates the characteristics of power state 20	Power State 20 Descriptor (PSD20)	
2751-2720	V		Indicates the characteristics of power state 21	Power State 21 Descriptor (PSD21)	
2783-2752	V		Indicates the characteristics of power state 22	Power State 22 Descriptor (PSD22)	
2815-2784	V		Indicates the characteristics of power state 23	Power State 23 Descriptor (PSD23)	
2847-2816	V		Indicates the characteristics of power state 24	Power State 24 Descriptor (PSD24)	
2879-2848	V		Indicates the characteristics of power state 25	Power State 25 Descriptor (PSD25)	
2911-2880	V		Indicates the characteristics of power state 26	Power State 26 Descriptor (PSD26)	
2943-2912	V		Indicates the characteristics of power state 27	Power State 27 Descriptor (PSD27)	
2975-2944	V		Indicates the characteristics of power state 28	Power State 28 Descriptor (PSD28)	
3007-2976	V		Indicates the characteristics of power state 29	Power State 29 Descriptor (PSD29)	
3039-3008	V		Indicates the characteristics of power state 30	Power State 30 Descriptor (PSD30)	
3071-3040	V		Indicates the characteristics of power state 31	Power State 31 Descriptor (PSD31)	
3075	F	05h	Data striped at 128 KB, value shown is reported as 2^ (CAP.MPSMIN)	Internal stripe size	
3095-3076	V	Varies	Shows healthy status or error code	Health indicator	
3096	V	Varies	Reads current negotiated PCIe* link speed, as reported by PXLS register (PXCAP + 12h), bits[3:0]	Current PCIe* Link Speed field (CLS)	
3097	V	Varies	Reads current negotiated PCIe* Link Width as reported by PXLS register (PXCAP + 12h), bits[9:4]		
4095-3098	V	NA	Range of bytes is allocated for vendor specific usage	Vendor Specific (VS)	

NOTES:

F = Fixed. The content of the word is fixed and does not change. For removable media devices, these values may change when media is removed or changed.

V = Variable. The state of at least one bit in a word is variable and may change depending on the state of the device or the commands executed by the device.

X = F or V. The content of the word may be fixed or variable.



Table 22: Power State Descriptor

Bytes	F = Fixed V = Variable X = Both	Default Value	Interpretation Description		
255-125				Reserved	
124-120	F	Oh	Indicates the relative write latency associated with this power state	Relative Write Latency (RWL)	
119-117				Reserved	
116-112	F	Oh	Indicates the relative write throughput associated with this power state	Relative Write Throughput (RWT)	
111-109				Reserved	
108-104	F	Oh	Indicates the relative read latency associated with this power state	Relative Read Latency (RRL)	
103-101				Reserved	
100-96	F	Oh	Indicates the relative read throughput associated with this power state.	Relative Read Throughput (RRT)	
95-64	F	Oh	Indicates the maximum exit latency in microseconds associated with exiting this power state.	Exit Latency (EXLAT)	
63-32	F	Oh	Indicates the maximum entry latency in microseconds associated with entering this power state	Entry Latency (ENLAT)	
31-16				Reserved	
15-00	F	09C4h	Indicates the maximum power consumed by the NVM subsystem in this power state. The power in Watts is equal to the value in this field multiplied by 0.01	Maximum Power (MP)	

Table 23: Identify Namespace

Bytes	F = Fixed V = Variable X = Both	Default Value	Interpretation	Description
7-0	V	varies	Indicates the total size of the namespace in logical blocks.	Namespace Size (NSZE)
15-8	V	varies	Indicates the maximum number of logical blocks that may be allocated in the namespace at any point in time	Namespace Capacity (NCAP)
23-16	V	varies	Indicates the current number of logical blocks allocated in the namespace	Namespace Utilization (NUSE)
24	F 00h Indicates thin provisioning is not supported		Namespace Features (NSFEAT)	
25	F	06h	Defines the number of supported LBA size and metadata size combinations supported by the namespace	Number of LBA Formats (NLBAF)
26	V	00h	Indicates metadata transferred with the extended data LBA or in separate buffer	Formatted LBA Size (FLBAS)
27	F	03h	Indicates support for metadata transferred with the extended data LBA and in separate buffer – both are supported	Metadata Capabilities (MC)



Bytes	F = Fixed V = Variable X = Both	Default Value	Interpretation	Description
28	V	11h	Indicates PI supports Type 1,2,3 with PI transferred as the first 8 bytes	End-to-end Data Protection Capabilities (DPC)
29	х	00h	Indicates type settings for the namespace	End-to-end Data Protection Type Settings (DPS)
127-30				Reserved
131-128	V	MS:0, LBADS:9, RP:2	Indicates the LBA format 0 that is supported by the controller	LBA Format 0 Support (LBAF0)
135-132	V	MS:8, LBADS:9, RP:2	Indicates the LBA format 1 that is supported by the controller	LBA Format 1 Support (LBAF1)
139-136	V	MS:16, LBADS:9, RP:2	Indicates the LBA format 2 that is supported by the controller	LBA Format 2 Support (LBAF2)
143-140	V	MS:0, LBADS:12, RP:0	Indicates the LBA format 3 that is supported by the controller	LBA Format 3 Support (LBAF3)
147-144	V	MS:8, LBADS:12, RP:0	Indicates the LBA format 4 that is supported by the controller	LBA Format 4 Support (LBAF4)
151-148	V	MS:64, LBADS:12, RP:0	Indicates the LBA format 5 that is supported by the controller	LBA Format 5 Support (LBAF5)
155-152	V	MS:128, LBADS:12, RP:0	Indicates the LBA format 6 that is supported by the controller	LBA Format 6 Support (LBAF6)
159-156		Not supported	Indicates the LBA format 7 that is supported by the controller	LBA Format 7 Support (LBAF7)
163-160		Not supported	Indicates the LBA format 8 that is supported by the controller	LBA Format 8 Support (LBAF8)
167-164		Not supported	Indicates the LBA format 9 that is supported by the controller	LBA Format 9 Support (LBAF9)
171-168		Not supported	Indicates the LBA format 10 that is supported by the controller	LBA Format 10 Support (LBAF10)
175-172		Not supported	Indicates the LBA format 11 that is supported by the controller	LBA Format 11 Support (LBAF11)
179-176		Not supported	Indicates the LBA format 12 that is supported by the controller	LBA Format 12 Support (LBAF12)
183-180		Not supported	Indicates the LBA format 13 that is supported by the controller	LBA Format 13 Support (LBAF13)
187-184		Not supported	Indicates the LBA format 14 that is supported by the controller	LBA Format 14 Support (LBAF14)
191-188		Not supported	Indicates the LBA format 15 that is supported by the controller	LBA Format 15 Support (LBAF15)
383-192		Not supported		Reserved
4095-384		Not supported	Range of bytes is allocated for vendor specific usage	Vendor Specific (VS)

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X = **F** or **V**. The content of the word may be fixed or variable.



Table 24: LBA Format Data Structure

Bytes	F = Fixed V = Variable X = Both	Default Value	Interpretation	Description
31-26				Reserved
25-24	V	Varies (2,0)	Relative Performance ranging from "best" to "degraded"	Relative Performance (RP)
23-16	V	Varies (9 and 12)	Indicates the LBA data size supported. The value is reported in terms of a power of two (2^n)	LBA Data Size (LBADS)
15-00	V	Varies (0, 8, 16,64, 128)	Indicates the number of metadata bytes provided per LBA based on the LBA Data Size indicated.	Metadata Size (MS)

NOTES:

F = Fixed. The content of the word is fixed and does not change. For removable media devices, these values may change when media is removed or changed.

V = Variable. The state of at least one bit in a word is variable and may change depending on the state of the device or the commands executed by the device.

X = F or V. The content of the word may be fixed or variable.



Appendix B PCIe ID

Table 25: PCIe ID

ID name	Description	Add-in Card	2.5-inc FF	PCIe Register Location	Identify Controller Location	Vital Product Data Location
Vendor ID (VID)	Vendor ID assigned by PCI- SIG	0x8086	0x8086	PCI Header Offset 00h (bits 15:00)	Bytes 01:00h	Address 3, (size 2B)
Device ID (DID)	Device ID assigned by vendor	0x0953	0x0953	PCI Header Offset 00h (bits 31:16)	NA	NA
Subsystem Vendor ID	Indicates Sub- system vendor ID	0x8086	0x8086	PCI Header Offset 2Ch (bits 15:00)	Bytes 03:02h	NA
Subsystem ID	Sub-system identifier	0x3704	0x3705	PCI Header Offset 2Ch (bits 31:16)	NA	NA



Appendix C SCSI Command Translation

Following SCSI commands are supported:

- Read 6,10,12,16
- Inquiry
- Mode Sense 6,10
- Mode Select 6.10
- Log Sense
- Read Capacity 10,16
- Report LUNs
- Request Sense
- Start Stop Unit
- Test Unit Ready
- Write Buffer
- Unmap

NOTES: Refer to NVM Express: SCSI Translation Reference doc under nvmexpress.org



Appendix D Add-in Card LED Decoder

Table 26: LED Functionality

LED	Description	Blink Behavior
LED 1(Amber)	Shows IO activity	Blinks at the rate of 250msec high, 250msec low with IO activity
LED 2 (Red)	Drive fail indicator	Solid red if drive is in disabled logical mode
LED 3 (Yellow)	Drive pre-fail indicator	Solid yellow if any of the critical warnings in log page 0x02 is triggered
LED 4 (Green)	Drive health indicator	Solid green when drive is healthy

Figure A-1 LED Location



Note: 2.5-inch Form Factor does not contain LEDs.